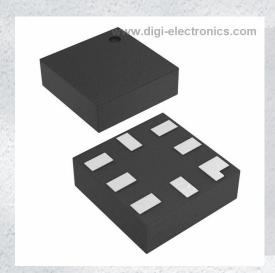


FXMAR2102UMX-F106 Datasheet



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DiGi Electronics Part Number FXMAR2102UMX-F106-DG

Manufacturer onsemi

Manufacturer Product Number FXMAR2102UMX-F106

Description IC TRANSLTR BIDIRECTIONAL 8UMLP

Detailed Description Voltage Level Translator Bidirectional 1 Circuit 2 Ch

annel 50MHz 8-UMLP (1.2x1.4)



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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
FXMAR2102UMX-F106	onsemi
Series:	Product Status:
	Active
Translator Type:	Channel Type:
Voltage Level	Bidirectional
Number of Circuits:	Channels per Circuit:
1	2
Voltage - VCCA:	Voltage - VCCB:
1.65 V ~ 5.5 V	1.65 V ~ 5.5 V
Input Signal:	Output Signal:
Output Type:	Data Rate:
Open Drain, Tri-State	50MHz
Operating Temperature:	Features:
-40°C ~ 85°C (TA)	Auto-Direction Sensing
Mounting Type:	Package / Case:
Surface Mount	8-UFQFN
Supplier Device Package:	Base Product Number:
8-UMLP (1.2x1.4)	FXMAR2102

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	

8542.39.0001



Dual Supply, 2-Bit Voltage Translator / Isolator for I²C Applications

FXMAR2102

Description

The FXMAR2102 is a high-performance configurable dual-voltage-supply translator for bi-directional voltage translation over a wide range of input and output voltages levels. The FXMAR2102 also works in a push-pull environment.

It is intended for use as a voltage translator between I^2C -Bus compliant masters and slaves. Internal 10 k Ω pull-up resistors are provided.

The device is designed so the A port tracks the V_{CCA} level and the B port tracks the V_{CCB} level. This allows for bi–directional A/B–port voltage translation between any two levels from 1.65 V to 5.5 V. V_{CCA} can equal V_{CCB} from 1.65 V to 5.5 V. Either V_{CC} can be powered–up first. Internal power–down control circuits place the device in 3–state if either V_{CC} is removed.

The two ports of the device have automatic direction-sense capability. Either port may sense an input signal and transfer it as an output signal to the other port.

Features

- Bi-Directional Interface between Any Two Levels: 1.65 V to 5.5 V
- No Direction Control Needed
- Internal 10 k Ω Pull-Up Resistors
- ullet System GPIO Resources Not Required when OE Tied to V_{CCA}
- I²C Bus Isolation
- A/B Port $V_{OL} = 175 \text{ mV}$ (Typical), $V_{IL} = 150 \text{ mV}$, $I_{OL} = 6 \text{ mA}$
- Open-Drain Inputs / Outputs
- Works in Push Pull Environment
- Accommodates Standard–Mode and Fast–Mode I²C–Bus Devices
- Supports I²C Clock Stretching & Multi–Master
- Fully Configurable: Inputs and Outputs Track V_{CC}
- Non-Preferential Power-Up; Either V_{CC} Can Power-Up First
- Outputs Switch to 3-State if Either V_{CC} is at GND
- Tolerant Output Enable: 5 V
- Packaged in 8-Terminal Leadless MicroPak[™] (1.6 mm x 1.6 mm) and Ultrathin MLP (1.2 mm x 1.4 mm)
- ESD Protection Exceeds:
 - B Port: 8 kV HBM ESD (vs. GND & vs. V_{CCB})
 - All Pins: 4 kV HBM ESD (per JESD22-A114)
 - ◆ 2 kV CDM (per JESD22–C101)





MARKING DIAGRAM



BU = Device Code

&K = 2-Digits Lot Run Traceability Code

&2 = 2-Digit Date Code&Z = Assembly Plant Code

ORDERING INFORMATION

See detailed ordering and shipping information on page 13 of this data sheet.

BLOCK DIAGRAM

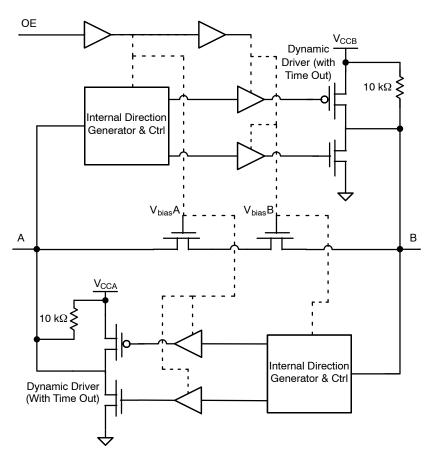
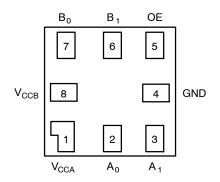


Figure 1. Block Diagram, 1 of 2 Channels

PIN CONFIGURATION



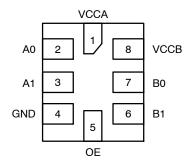


Figure 2. MicroPak (Top-Through View)

Figure 3. UMLP (Top-Through View)

PIN DEFINITIONS

Pin No.	Name	Description	
1	V _{CCA}	A-Side Power Supply	
2, 3	A ₀ , A ₁	A–Side Inputs or 3–State Outputs	
4	GND	Ground	
5	OE	Output Enable Input	
6, 7	B ₁ , B ₀	B-Side Inputs or 3-State Outputs	
8	V _{CCB}	B-Side Power Supply	

TRUTH TABLE

Control	
OE (Note 1)	Outputs
LOW Logic Level	3-State
HIGH Logic Level	Normal Operation

^{1.} If the OE pin is driven LOW, the FXMAR2102 is disabled and the A_0 , A_1 , B_0 , and B_1 pins (including dynamic drivers) are forced into 3–state and all four 10 k Ω internal pull–up resisters are decoupled from their respective V_{CC} .

ABSOLUTE MAXIMUM RATINGS

Symbol	Pa	Min	Max	Unit	
V_{CCA}, V_{CCB}	Supply Voltage		-0.5	7.0	V
V _{IN}	DC Input Voltage	A Port	-0.5	7.0	1
		B Port	-0.5	7.0	
		Control Input (OE)	-0.5	7.0	
Vo	Output Voltage (Note 2)	A _n Outputs 3-State	-0.5	7.0	V
		B _n Outputs 3-State	-0.5	7.0	
		A _n Outputs Active	-0.5	V _{CCA} + 0.5 V	
		B _n Outputs Active	-0.5	V _{CCB} + 0.5 V	1
I _{IK}	DC Input Diode Current	At V _{IN} < 0 V	-	–50	mA
I _{OK}	DC Output Diode Current	At V _O < 0 V	-	–50	mA
		At V _O > V _{CC}	-	+50	1
I _{OH} / I _{OL}	DC Output Source/Sink Current		-50	+50	mA
I _{CC}	DC V _{CC} or Ground Current per Supp	oly Pin	-	±100	mA
P_{D}	Power Dissipation	At 400 KHz	-	0.129	mW
T _{STG}	Storage Temperature Range		-65	+150	°C
ESD	Electrostatic Discharge Capability	Human Body Model, B-Port Pins	-	8	kV
		Human Body Model, All Pins (JESD22-A114)	-	4	
		Charged Device Mode, JESD22-C101	-	2	1

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

RECOMMENDED OPERATING CONDITIONS

Symbol	Pa	Parameter			Unit
V_{CCA}, V_{CCB}	Power Supply Operating		1.65	5.50	V
V _{IN}	Input Voltage (Note 3)	A-Port	0	5.5	V
		B-Port	0	5.5	
		Control Input (OE)	0	V _{CCA}	
Θ_{JA}	Thermal Resistance	8-Lead MicroPak	-	279	°C/W
		8-Lead Ultrathin MLP	-	302	
T _A	Free Air Operating Temperature		-40	+85	°C

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

^{2.} I_O absolute maximum rating must be observed.

^{3.} All unused inputs and I/O pins must be held at V_{CCI} or GND. V_{CCI} is the V_{CC} associated with the input side.

FUNCTIONAL DESCRIPTION

Power-Up / Power-Down Sequencing

FXM translators offer an advantage in that either V_{CC} may be powered up first. This benefit derives from the chip design. When either V_{CC} is at 0 V, outputs are in a high-impedance state. The control input (OE) is designed to track the V_{CCA} supply. A pull-down resistor tying OE to GND should be used to ensure that bus contention, excessive currents, or oscillations do not occur during power-up/-down. The size of the pull-down resistor is based upon the current-sinking capability of the device driving the OE pin.

The recommended power-up sequence is:

- 1. Apply power to the first V_{CC} .
- 2. Apply power to the second V_{CC} .
- 3. Drive the OE input HIGH to enable the device.

The recommended power-down sequence is:

- 1. Drive OE input LOW to disable the device.
- 2. Remove power from either V_{CC} .
- 3. Remove power from the other V_{CC} .

NOTE:

4. Alternatively, the OE pin can be hardwired to V_{CCA} to save GPIO pins. If OE is hardwired to V_{CCA} , either V_{CC} can be powered up or down first.

APPLICATION CIRCUIT

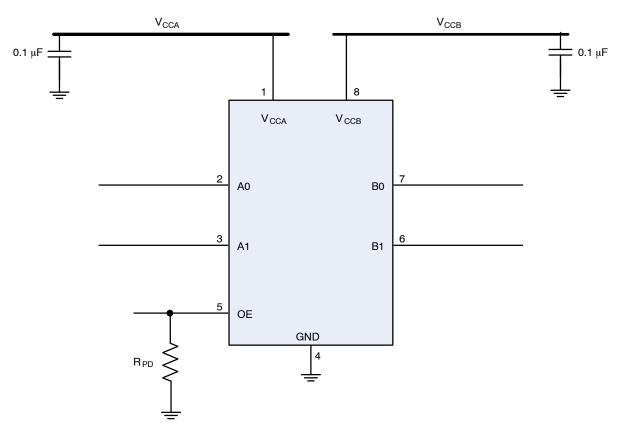


Figure 4. Application Circuit

APPLICATION NOTES

The FXMAR2102 has open-drain I/Os and includes a total of four 10 k Ω internal pull-up resistors (R_{PU}) on each of the four data I/O pins, as shown in Figure 4. If a pair of data I/O pins (A_n/B_n) is not used, both pins should disconnected, eliminating unwanted current flow through the internal RPUs. External RPUs can be added to the I/Os to reduce the total RPU value, depending on the total bus capacitance. The designer is free to lower the total pull-up resistor value to meet the maximum I²C edge rate per the I²C specification (UM10204 rev. 03, June 19, 2007). For example, according to the I2C specification, the maximum edge rate (30% - 70%) during Fast Mode (400 kbit/s) is 300 ns. If the bus capacitance is approaching the maximum 400 pF, a lower total R_{PII} value helps keep the rise time below 300 ns (Fast Mode). Likewise, the I²C specification also specifies a minimum Serial Clock Line High Time of 600 ns during Fast Mode (400 kHz). Lowering the total RPU also helps increase the SCL High Time. If the bus capacitance approaches 400 pF, it may make sense to use the FXMA2102, which does not contain internal RPUs. Then calculate the ideal external R_{PU} value.

NOTE:

5. Section 7.1 of the I²C specification provides an excellent guideline for pull–up resistor sizing.

Theory of Operation

The FXMAR2102 is designed for high-performance level shifting and buffer / repeating in an I²C application. Figure 1 shows that each bi-directional channel contains two series-Npassgates and two dynamic drivers. This hybrid architecture is highly beneficial in an I²C application where auto-direction is a necessity.

For example, during the following three I²C protocol events:

- Clock Stretching
- Slave's ACK Bit (9th bit = 0) following a Master's Write Bit (8th bit = 0)
- Clock Synchronization and Multi-Master Arbitration

The bus direction needs to change from master-to-slave to slave-to-master without the occurrence of an edge. If there is an I²C translator between the master and slave in these examples, the I²C translator must change direction when both A and B ports are LOW. The Npassgates can accomplish this task very efficiently because, when both A and B ports are LOW, the Npassgates act as a low-resistive short between the A and B ports.

Due to I²C's open-drain topology, I²C masters and slaves are not push/pull drivers. Logic LOWs are "pulled down" (Isink), while logic HIGHs are "let go" (3-state). For example, when the master lets go of SCL (SCL always comes from the master), the rise time of SCL is largely determined by the RC time constant, where R = RPU and C = the bus capacitance. If the FXMAR2102 is attached to the master [on the A port] and there is a slave on the B port,

the Npassgates act as a low-resistive short between both ports until either of the port's $V_{\rm CC}/2$ thresholds are reached. After the RC time constant has reached the $V_{\rm CC}/2$ threshold of either port, the port's edge detector triggers both dynamic drivers to drive their respective ports in the LOW-to-HIGH (LH) direction, accelerating the rising edge. The resulting rise time resembles the scope shot in Figure 5. Effectively, two distinct slew rates appear in rise time. The first slew rate (slower) is the RC time constant of the bus. The second slew rate (much faster) is the dynamic driver accelerating the edge.

If both the A and B ports of the translator are HIGH, a high-impedance path exists between the A and B ports because both the Npassgates are turned off. If a master or slave device decides to pull SCL or SDA LOW, that device's driver pulls down (I_{sink}) SCL or SDA until the edge reaches the A or B port $V_{CC}/2$ threshold. When either the A or B port threshold is reached, the port's edge detector triggers both dynamic drivers to drive their respective ports in the HIGH-to-LOW (HL) direction, accelerating the falling edge.

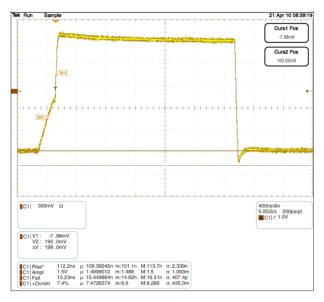


Figure 5. Waveform C: 600 pF, Total R_{PU}: 2.2 k Ω

V_{OL} vs. I_{OL}

The I^2C specification mandates a maximum V_{IL} (I_{OL} of 3 mA) of $V_{CC} \cdot 0.3$ and a maximum V_{OL} of 0.4 V. If there is a master on the A port of an I^2C translator with a V_{CC} of 1.65 V and a slave on the I^2C translator B port with a V_{CC} of 3.3 V, the maximum V_{IL} of the master is (1.65 V x 0.3) 495 mV. The slave could legally transmit a valid logic LOW of 0.4 V to the master.

If the I^2C translator's channel resistance is too high, the voltage drop across the translator could present a V_{IL} to the master greater than 495 mV. To complicate matters, the I^2C specification states that 6 mA of I_{OL} is recommended for bus

capacitances approaching 400 pF. More I_{OL} increases the voltage drop across the I^2C translator. The I^2C application benefits when I^2C translators exhibit low V_{OL} performance.

Figure 6 depicts typical FXMAR2102 V_{OL} performance vs. the competition, given a 0.4 V V_{IL} .

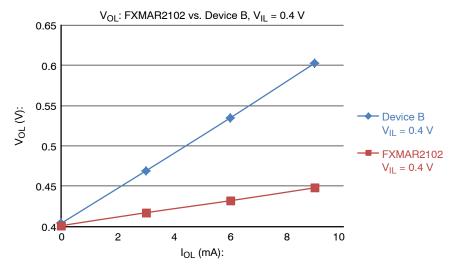


Figure 6. Device Comparison

I²C-Bus Isolation

The FXMAR2102 supports I²C–Bus isolation for the following conditions:

- Bus isolation if bus clear
- Bus isolation if either V_{CC} goes to ground

Bus Clear

Because the I²C specification defines the minimum SCL frequency of DC, the SCL signal can be held LOW forever; however, this condition shuts down the I²C bus. The I²C specification refers to this condition as "Bus Clear". In Figure 7; if slave #2 holds down SCL forever, the master and slave #1 are not able to communicate because the FXMAR2102 passes the SCL stuck–LOW condition from

slave #2 to slave #1 and as the master. However, if the OE pin is pulled LOW (disabled), both ports (A and B) are 3-stated. This results in the FXMAR2102 isolating slave #2 from the master and slave #1, allowing full communication between the master and slave #1.

V_{CC} to GND

If slave #2 is a camera that is suddenly removed from the I^2C bus, resulting in V_{CCB} transitioning from a valid V_{CC} (1.65 V – 5.5 V) to 0 V; the FXMAR2102 automatically forces SCL and SDA on both its A and B ports into 3–state. Once V_{CCB} has reached 0 V, full I^2C communication between the master and slave #1 remains undisturbed.

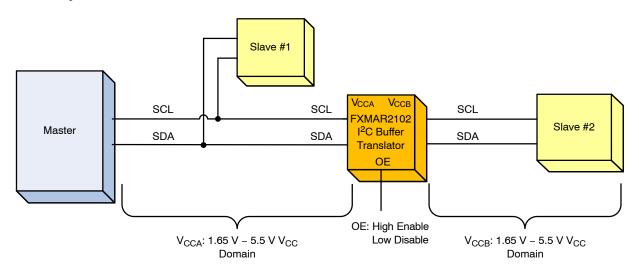


Figure 7. Bus Isolation

DC ELECTRICAL CHARACTERISTICS ($T_A = -40$ °C to +85°C)

Parameter	Condition		V _{CCA} (V)	V _{CCB} (V)	Min	Тур	Max	Unit
High Level Input	Data Inp	outs A _n	1.65 – 5.50	1.65 – 5.50	V _{CCA} - 0.4	=	-	V
Voltage A	Control	Control Input OE		1.65 – 5.50	0.7 x V _{CCA}	-	-	
High Level Input Voltage B	Data Inp	outs B _n	1.65 – 5.50	1.65 – 5.50	V _{CCB} – 0.4	-	-	V
Low Level Input	Data Inp	outs A _n	1.65 – 5.50	1.65 – 5.50	-	-	0.4	V
Voltage A	Control	Input OE	1.65 – 5.50	1.65 – 5.50	-	_	0.3 x V _{CCA}	
Low Level Input Voltage B	Data Inp	outs B _n	1.65 – 5.50	1.65 – 5.50	-	-	0.4	V
Low Level Output	V _{IL} = 0.	15 V	1.65–5.50	1.65–5.50	-	-	0.4	V
Voltage	I _{OL} = 6 i	mA	1			-		
Input Leakage Current			1.65 – 5.50	1.65 – 5.50	-	-	±1.0	μΑ
Power-Off Leakage Current	A _n	V _{IN} or V _O = 0 V to 5.5 V	0	5.50	-	-	±2.0	μΑ
	B _n	V _{IN} or V _O = 0 V to 5.5 V	5.50	0	-	-	±2.0	
3-State Output Leakage	A _n , B _n	V _O = 0 V to 5.5 V, OE = V _{IL}	5.50	5.50	-	-	±2.0	μΑ
(Note 7)	A _n	V _O = 0 V to 5.5 V, OE = Don't Care	5.50	0	-	-	±2.0	
	B _n	V _O = 0 V to 5.5 V, OE = Don't Care	0	5.50	-	-	±2.0	
Quiescent Supply Current (Note 8, 9)	$V_{IN} = V_0$	$_{CCI}$ or Floating, $I_{O} = 0$	1.65 – 5.50	1.65 – 5.50	-	_	5.0	μΑ
Quiescent Supply Current (Note 8)		V _{IN} = V _{CCI} or GND, I _O = 0, OE = V _{IL}		1.65 – 5.50	-	_	5.0	μΑ
Quiescent Supply	V _{IN} = 5.5 V or GND, I _O = 0, OE = Don't Care, B _n to A _n		0	1.65 – 5.50	-	_	-2.0	μΑ
Current (Note 7)			1.65 – 5.50	0	-	-	2.0	
Quiescent Supply		$V_{IN} = 5.5 \text{ V or GND}, I_{O} = 0,$		0	-	=	-2.0	μΑ
Current (Note /)	UE = D	on t Care, A _n to B _n	0	1.65 – 5.50	-	=	2.0	
Resistor Pull-up Value	VCCA 8	k VCCB Sides	1.65–5.50	1.65 – 5.50	-	10	-	Ω
	High Level Input Voltage A High Level Input Voltage B Low Level Input Voltage A Low Level Input Voltage B Low Level Output Voltage Input Leakage Current Power-Off Leakage Current 3-State Output Leakage (Note 7) Quiescent Supply Current (Note 8, 9) Quiescent Supply Current (Note 8) Quiescent Supply Current (Note 7) Quiescent Supply Current (Note 7) Resistor Pull-up	High Level Input Data Input	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	High Level Input Voltage A Data Inputs A _n 1.65 – 5.50	Data Input	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	High Level Input Voltage A	High Level Input Voltage A

^{6.} This table contains the output voltage for static conditions. Dynamic drive specifications are given in Dynamic Output Electrical Characteristics.

7. "Don't Care" indicates any valid logic level.

8. V_{CCI} is the V_{CC} associated with the input side.

9. Reflects current per supply, V_{CCA} or V_{CCB}.

DYNAMIC OUTPUT ELECTRICAL CHARACTERISTICS

OUTPUT RISE / FALL TIME (Note 10) (Output load: $C_L = 50$ pF, $R_{PU} = NC$, push / pull driver, and $T_A = -40$ °C to +85°C.)

		V _{CCO} (Note 11)				
		4.5 to 5.5 V	3.0 to 3.6 V	2.3 to 2.7 V	1.65 to 1.95 V	
Symbol	Parameter	Тур	Тур	Тур	Тур	Unit
t _{rise}	Output Rise Time; A Port, B Port (Note 12)	3	4	5	7	ns
t _{fall}	Output Fall Time; A Port, B Port (Note 13)	1	1	1	1	ns

^{10.} Output rise and fall times guaranteed by design simulation and characterization; not production tested.

DYNAMIC OUTPUT ELECTRICAL CHARACTERISTICS

MAXIMUM DATA RATE (Note 14) (Output load: $C_L = 50$ pF, $R_{PU} = NC$, push / pull driver, and $T_A = -40$ °C to +85°C.)

			V _{CCB}				
		4.5 to 5.5 V	3.0 to 3.6 V	2.3 to 2.7 V	1.65 to 1.95 V]	
V _{CCA}	Direction		Mini	mums	-	Unit	
4.5 V to 5.5 V	A to B	50	50	40	30	MHz	
	B to A	50	50	40	40	1	
3.0 V to 3.6 V	A to B	50	50	40	19	MHz	
	B to A	50	50	40	40	1	
2.3 V to 2.7 V	A to B	40	40	30	19	MHz	
	B to A	40	40	30	30		
1.65 V to 1.95 V	A to B	40	40	30	19	MHz	
	B to A	30	30	19	19		

^{14.}F-toggle guaranteed by design simulation; not production tested.

^{11.} V_{CCO} is the V_{CC} associated with the output side. 12. See Figure 12.

^{13.} See Figure 13.

 $\textbf{AC CHARACTERISTICS} \text{ (Note 15) (Output load: } C_L = 50 \text{ pF, } R_{PU} = NC, \text{ push / pull driver, and } T_A = -40^{\circ}C \text{ to } +85^{\circ}C.)$

		V _{CCB}								
		4.5 to	5.5 V	3.0 to	3.6 V	2.3 to	2.7 V	1.65 to	1.95 V	
Symbol	Parameter	Тур	Max	Тур	Max	Тур	Max	Тур	Max	Unit
CCA = 4.5	to 5.5 V									
t _{PLH}	A to B	1	3	1	3	1	3	1	3	ns
	B to A	1	3	2	4	3	5	4	7	
t _{PHL}	A to B	2	4	3	5	4	6	5	7	ns
	B to A	2	4	2	5	2	6	5	7	1
t _{PZL}	OE to A	4	5	6	10	5	9	7	15	ns
	OE to B	3	5	4	7	5	8	10	15	1
t _{PLZ}	OE to A	65	100	65	105	65	105	65	105	ns
	OE to B	5	9	6	10	7	12	9	16	1
t _{skew}	A Port, B Port (Note 16)	0.50	1.50	0.50	1.00	0.50	1.00	0.50	1.00	ns
/ _{CCA} = 3.0	to 3.6 V									
t _{PLH}	A to B	2.0	5.0	1.5	3.0	1.5	3.0	1.5	3.0	ns
	B to A	1.5	3.0	1.5	4.0	2.0	6.0	3.0	9.0	1
t _{PHL}	A to B	2.0	4.0	2.0	4.0	2.0	5.0	3.0	5.0	ns
	B to A	2.0	4.0	2.0	4.0	2.0	5.0	3.0	5.0	
t _{PZL}	OE to A	4.0	8.0	5.0	9.0	6.0	11.0	7.0	15.0	ns
	OE to B	4.0	8.0	6.0	9.0	8.0	11.0	10.0	14.0	
t _{PLZ}	OE to A	100	115	100	115	100	115	100	115	ns
	OE to B	5	10	4	8	5	10	9	15	
t _{skew}	A Port, B Port (Note 16)	0.5	1.5	0.5	1.0	0.5	1.0	0.5	1.0	ns
/ _{CCA} = 2.3	to 2.7 V	•		•	•	•	•	•	•	
t _{PLH}	A to B	2.5	5.0	2.5	5.0	2.0	4.0	1.0	3.0	ns
	B to A	1.5	3.0	2.0	4.0	3.0	6.0	5.0	10.0	
t _{PHL}	A to B	2.0	5.0	2.0	5.0	2.0	5.0	3.0	6.0	ns
	B to A	2.0	5.0	2.0	5.0	2.0	5.0	3.0	6.0	
t _{PZL}	OE to A	5.0	10.0	5.0	10.0	6.0	12.0	9.0	18.0	ns
	OE to B	4.0	8.0	4.5	9.0	5.0	10.0	9.0	18.0	1
t _{PLZ}	OE to A	100	115	100	115	100	115	100	115	ns
	OE to B	65	110	65	110	65	115	12	25	
t _{skew}	A Port, B Port (Note 16)	0.5	1.5	0.5	1.0	0.5	1.0	0.5	1.0	ns
/ _{CCA} = 1.65	5 to 1.95 V	•	•			•			•	
t _{PLH}	A to B	4	7	4	7	5	8	5	10	ns
	B to A	1.0	2.0	1.0	2.0	1.5	3.0	5.0	10.0	
t _{PHL}	A to B	5	8	3	7	3	7	3	7	ns
	B to A	4	8	3	7	3	7	3	7	
t _{PZL}	OE to A	11	15	11	14	14	28	14	23	ns
	OE to B	6	14	6	14	6	14	9	16	1
t _{PLZ}	OE to A	75	115	75	115	75	115	75	115	ns
	OE to B	75	115	75	115	75	115	75	115	1
t _{skew}	A Port, B Port (Note 16)	0.5	1.5	0.5	1.0	0.5	1.0	0.5	1.0	ns

^{15.}AC characteristics are guaranteed by design and characterization.

^{16.} Skew is the variation of propagation delay between output signals and applies only to output signals on the same port (A_n or B_n) and switching with the same polarity (LOW-to-HIGH or HIGH-to-LOW) (see Figure 15). Skew is guaranteed; not production tested.

CAPACITANCE $(T_A = +25^{\circ}C.)$

Symbol	Parameter	Condition	Тур	Unit
C _{IN}	Input Capacitance Control Pin (OE)	V _{CCA} = V _{CCB} = GND	2.2	pF
C _{I/O}	Input/Output Capacitance, A _n , B _n	V _{CCA} = V _{CCB} = 5.0 V, OE = GND	13	pF

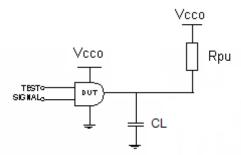


Figure 8. AC Test Circuit

Table 1. PROPAGATION DELAY TABLE (Note 17)

Test	Input Signal	Output Enable Control
t _{PLH} , t _{PHL}	Data Pulses	V _{CCA}
t_{PZL} (OE to A_n , B_n)	0 V	LOW to HIGH Switch
t _{PLZ} (OE to A _n , B _n)	0 V	HIGH to LOW Switch

^{17.} For t_{PZL} and t_{PLZ} testing, an external 2.2 k Ω pull-up resister to V_{CCO} is required in order to force the I/O pins high while OE is Low because when OE is low, the internal 10 k Ω RPUs are decoupled from their respective VCC's.

Table 2. AC LOAD TABLE

V _{cco}	C _L	R _L
1.8 ±0.15 V	50 pF	NC
2.5 ±0.2 V	50 pF	NC
3.3 ±0.3 V	50 pF	NC
5.0 ±0.5 V	50 pF	NC

TIMING DIAGRAMS

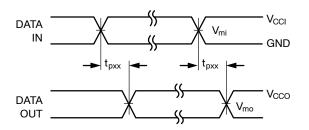


Figure 9. Waveform for Inverting and Non-Inverting Functions (Note 18)

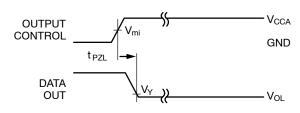


Figure 10. 3-STATE Output Low Enable Time (Note 18)

OUTPUT CONTROL	V _{CCA} V _{mi}	— GND
	t _{PLZ} —▶	— GND
DATA OUT	V _{OL}	

Figure 11. 3-STATE Output High Enable Time (Note 18)

Symbol	V _{CC}
V _{mi} (Note 19)	V _{CCI} / 2
V_{mo}	V _{CCO} / 2
V _X	0.5 x V _{CCO}
V_{Y}	0.1 x V _{CCO}

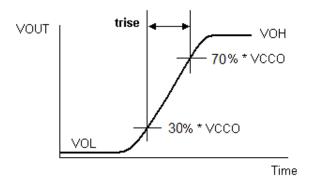


Figure 12. Active Output Rise Time

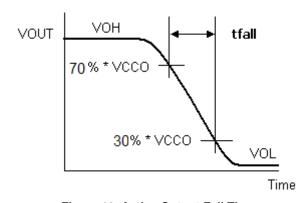


Figure 13. Active Output Fall Time

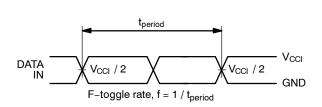


Figure 14. F-Toggle Rate

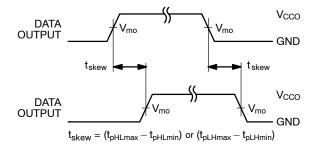


Figure 15. Output Skew Time

NOTES:

 $\begin{array}{l} 18. \ \, \mbox{Input} \ \, t_R = t_F = 2.0 \ \, \mbox{ns}, \ \, 10\% \ \, \mbox{to} \ \, 90\% \ \, \mbox{at} \ \, V_{IN} = 1.65 \ \, V \ \, \mbox{to} \ \, 1.95 \ \, V; \\ \mbox{Input} \ \, t_R = t_F = 2.0 \ \, \mbox{ns}, \ \, 10\% \ \, \mbox{to} \ \, 90\% \ \, \mbox{at} \ \, V_{IN} = 2.3 \ \, V \ \, \mbox{to} \ \, 2.7 \ \, V; \\ \mbox{Input} \ \, t_R = t_F = 2.5 \ \, \mbox{ns}, \ \, 10\% \ \, \mbox{to} \ \, 90\%, \ \, \mbox{at} \ \, V_{IN} = 3.0 \ \, V \ \, \mbox{to} \ \, 3.6 \ \, V \ \, \mbox{only}; \\ \mbox{Input} \ \, t_R = t_F = 2.5 \ \, \mbox{ns}, \ \, 10\% \ \, \mbox{to} \ \, 90\%, \ \, \mbox{at} \ \, V_{IN} = 4.5 \ \, V \ \, \mbox{to} \ \, 5.5 \ \, V \ \, \mbox{only}. \\ \mbox{19.} \ \, V_{CCI} = V_{CCA} \ \, \mbox{for control pin OE or} \ \, V_{mi} = (V_{CCA} \ \, / \ \, 2). \end{array}$

ORDERING INFORMATION

Part Number	Operating Temperature Range	Top Mark	Package	Packing Method [†]
FXMAR2102L8X	−40 to +85°C	BU	8-Lead MicroPak, 1.6 mm Wide (Pb-Free)	5000 / Tape & Reel
FXMAR2102UMX			8-Lead Ultrathin MLP, 1.2 mm x 1.4 mm (Pb-Free)	

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MicroPak is trademark of Semiconductor Components Industries, LLC (SCILLC) or its subsidiaries in the United States and/or other countries. onsemi is licensed by the Philips Corporation to carry the I^2C bus protocol.



MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS

SCALE 4:1

UQFN8, 1.40x1.20, 0.40P CASE 523AS **ISSUE B**

DATE 19 AUG 2021

NOTES:

MOLD CMPD

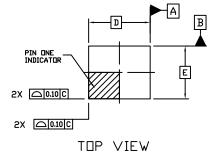
- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- CONTROLLING DIMENSION: MILLIMETERS 2.
- DIMENSION 6 APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.25MM FROM THE TERMINAL TIP.
- REFER TO SPECIFIC DEVICE DATA SHEET FOR PIN 1 NOTCH LOCATION.

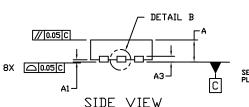
PACKAGE DUTLINE

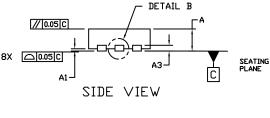
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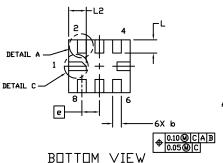
-0.45

0.40









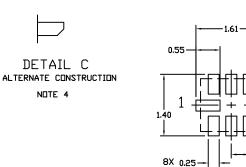


EXPOSED Cu



DETAIL A ALTERNATE CONSTRUCTIONS

	MILLIMETERS		
DIM	MIN.	MAX.	
Α	0.45	0.55	
A1	0.00	0.05	
A3	0.13 REF		
b	0.15	0.25	
D	1.40 BSC		
Ε	1.20 BSC		
e	0.40 BSC		
L	0.20	0.40	
L1		0.15	
L2	0.30	0.50	



RECOMMENDED MOUNTING FOOTPRINT *

GENERIC MARKING DIAGRAM*

XX = Specific Device Code M = Date Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "=", may or may not be present. Some products may not follow the Generic Marking.

For additional information on our Pb-Free strategy and soldering details, please download the $\square N$ Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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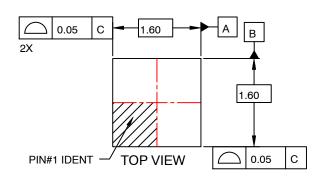
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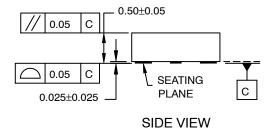


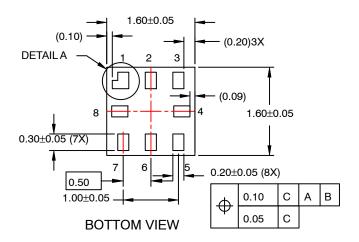
MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

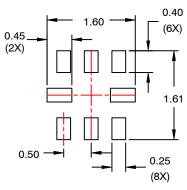
UQFN8 1.6X1.6, 0.5P CASE 523AY ISSUE O

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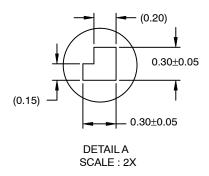




RECOMMENDED LAND PATTERN

NOTES:

- A. PACKAGE CONFORMS TO JEDEC MO-255 VARIATION UAAD.
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 2009.
- D. LAND PATTERN RECOMMENDATION IS EXISTING INDUSTRY LAND PATTERN.



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